NSN 5961-01-080-2406

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View Online at https://aerobasegroup.com/nsn/5961-01-080-2406

Overall Length:
Between 0.180 inches and 0.200 inches
Overall Diameter:
Between 0.110 inches and 0.125 inches
Internal Configuration:
Junction contact
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
1.00 milliamperes forward current, total rms minor
Special Features:
voltage; internal junction configuration: npn
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0